

TI Designs: TIDA-01359

具有更低噪声和失真的模拟音频放大器前端参考设计



说明

这一具有更低噪声和失真的模拟音频放大器前端参考设计展示了如何构建适用于 TPA32xx D 类放大器的音频前端。

该参考设计使用标准音频接口板 (AIB) 连接器来驱动 TPA32xx EVM 的两个差分音频输入。该音频前端具有 0dB、6dB 和 12dB 三个可选增益，且可将两个单端音频信号转换成两个全差分信号，以驱动 TPA32xx 的输入。

该音频前端的失真和噪声性能 (THD+N 比) 明显优于 TPA32xx 的 THD+N 比，这样可确保该音频前端不会对整个系统的性能造成降级。

资源

[TIDA-01359](#)
[OPA1632](#)

设计文件夹
产品文件夹



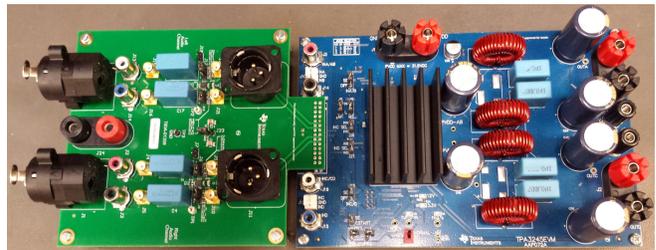
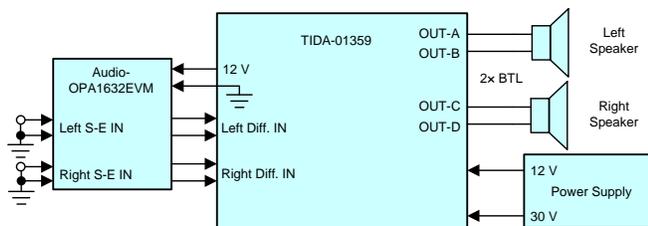
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特性

- 通过单个全差分放大器实现单端到差动的转换，可优化 THD+N 比
- 四个针对模拟输入的并联连接器：XLR 插孔、¼ 英寸立体声手机插孔、RCA 插孔和 SMA 插孔
- 可将增益调节至 0dB、6dB 和 12dB
- 除单端输入外，前端还接受差分输入
- 可匹配 TPA32xx 带宽的 100kHz 带宽
- 用于对输入进行直流阻断和用于对输出进行滤波的低失真电容器
- 单端输入阻抗在 0dB 增益下为 10kΩ，在 12dB 增益下可提高至 12.5kΩ
- 可通过 TPA32xx EVM 或外部电源（在没有 TPA32xx EVM 的情况下进行评估时）提供可选 12V 电源

应用

- 蓝光光盘™和 DVD 接收器
- 高端电视机
- 高端条形音箱
- 微型 Combo 系统
- 有源扬声器和低音炮



该 TI 参考设计末尾的重要声明表述了授权使用、知识产权问题和其他重要的免责声明和信息。

1 System Description

This reference design is an audio front end for a TPA32xx class-D amplifier. The OPA1632 is suited for high-end audio applications where minimizing noise and distortion is the primary concern.

This reference design was built and tested, and 4 节 shows the test results. The test board is referred to as the "Audio-TIDA01359EVM" board. The design files (GERBER, BOM, schematic and layout layers) are included in the reference design documentation found in the [TIDA-01359](#) product folder.

Traditionally, professional and high-end consumer audio equipment such as active speakers, high-end TV, and high-end soundbar systems are the primary applications.

Broader audio categories such as mini-combo systems, Blu-ray disc, and DVD receivers are concerned with high-quality audio and utilize high-performance devices such as the OPA1632 in the audio signal chain.

表 1 shows the key specifications.

1.1 Key System Specifications

表 1. Key System Specifications

PARAMETER	SPECIFICATIONS
Supply voltage	12-V TPA32xx AIB supply or external supply
THD+N	0.0003% with G = 0 dB, 1-kHz differential output, 2.54-V _{RMS} (100-W TPA3245 output into 4-Ω BTL)
Single-ended input impedance	≥ 10 kΩ
Bandwidth	2 Hz to 100 kHz

2 System Overview

2.1 Block Diagram

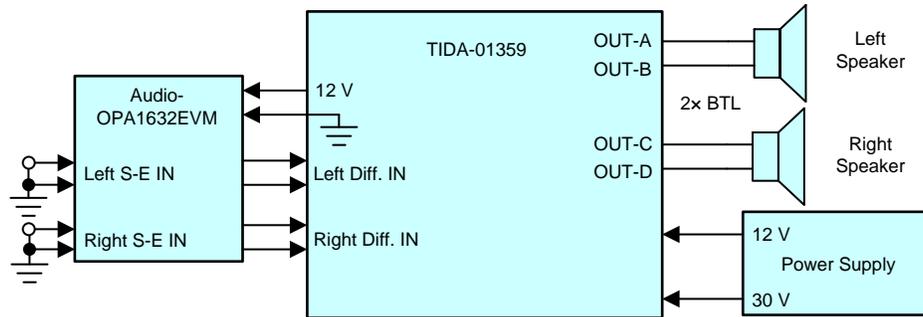


图 1. TIDA-01359 Block Diagram

2.2 System Design Theory

All performance plots in this section are measured data produced from the "Audio-TIDA01359EVM" board. The design files (GERBER, BOM, schematic and layout layers) are included in the reference design documentation found in the [TIDA-01359](#) product folder.

The most significant trade-off in this reference design is the input impedance versus the resistor thermal noise. Increasing resistors R11 and R12 in [图 5](#) increases the single-ended and differential input impedances but increases the noise at the amplifier output. To achieve the selectable gains of 0 dB, 6 dB, and 12 dB, the resistors R15 through R18 must increase proportionately, which further adds to the noise.

The minimum single-ended input impedance is 10 kΩ. For a single-ended input, the input impedance is higher than the R11 resistor because the input common-mode voltage of the amplifier is not constant. The changing OUT+ voltage is attenuated and fed back to the negative input of the amplifier, which forces the positive amplifier input to partially track the input voltage applied to R11. [公式 1](#) shows the single-ended input impedance as a function of R_f and R_g . R_g has a value of 7.5 kΩ to produce a single-ended input impedance of 10 kΩ with an amplifier gain of 0 dB.

$$Z_{in} = \frac{2R_g \left(1 + \frac{R_f}{R_g} \right)}{\left(2 + \frac{R_f}{R_g} \right)} \quad (1)$$

When $R_g = R_f = 7.5$ kΩ, the gain of the amplifier equals 0 dB and the broadband output noise and the relative contributions to the noise power are listed in [表 2](#).

表 2. Broadband Output Noise (Gain = 0 dB)

NOISE SOURCE	SPOT NOISE (nV/√Hz)	V _{RMS} WITH 100-Hz BW (μV)	RELATIVE POWER (%)
$R_g = 7.5$ kΩ	15.71	4.97	47.6
$R_f = 7.5$ kΩ	15.71	4.97	47.6
Amp current noise	4.24	1.34	3.5
Amp voltage noise	2.6	0.82	1.3
Total noise	22.77	7.2	100

With $R_g = 7.5 \text{ k}\Omega$ and $R_f = 15 \text{ k}\Omega$, the amplifier gain = 6 dB and the noise contributions are provided in the following 表 3.

表 3. Contributors to Broadband Output Noise (Gain = 6 dB)

NOISE SOURCE	SPOT NOISE (nV/ $\sqrt{\text{Hz}}$)	V_{RMS} WITH 100-Hz BW (μV)	RELATIVE POWER (%)
$R_g = 7.5 \text{ k}\Omega$	31.42	9.94	63
$R_f = 15 \text{ k}\Omega$	22.22	7.03	31.5
Amp current noise	8.49	2.68	4.6
Amp voltage noise	3.9	1.23	1
Total noise	39.6	12.52	100

When R_g equals $7.5 \text{ k}\Omega$ and R_f equals $30 \text{ k}\Omega$, the gain of the amplifier equals 12 dB. 表 4 lists the noise contributions.

表 4. Contributors to Broadband Output Noise (Gain = 12 dB)

NOISE SOURCE	SPOT NOISE (nV/ $\sqrt{\text{Hz}}$)	V_{RMS} WITH 100-Hz BW (μV)	RELATIVE POWER (%)
$R_g = 7.5 \text{ k}\Omega$	62.85	19.87	75
$R_f = 30 \text{ k}\Omega$	31.42	9.94	18.7
Amp current noise	16.97	5.37	5.5
Amp voltage noise	6.5	2.06	0.8
Total noise	72.58	22.95	100

See the *Noise analysis* section of the [Analysis of Fully-differential Amplifiers \[1\]](#) technical brief. This is sourced from the TI Analog Application Journal for the calculation of the noise components.

The broadband noise of the amplifier is approximately 5% of the total output noise power for all three gain configurations. Normally, the voltage noise of the amplifier is larger than the current noise, but the large resistor values increase the power of the current noise without changing the voltage noise. Hence, large gain-setting resistors have two adverse effects: The resistor noise dominates the amplifier noise above the corner frequency of the amplifier and the contribution of the current noise of the amplifier increases.

At low frequencies, the flicker noise of the amplifier dominates the noise contributions from the resistors. An HP3589A spectrum analyzer measured the spot noise for the three gain configurations and 图 2 shows the results.

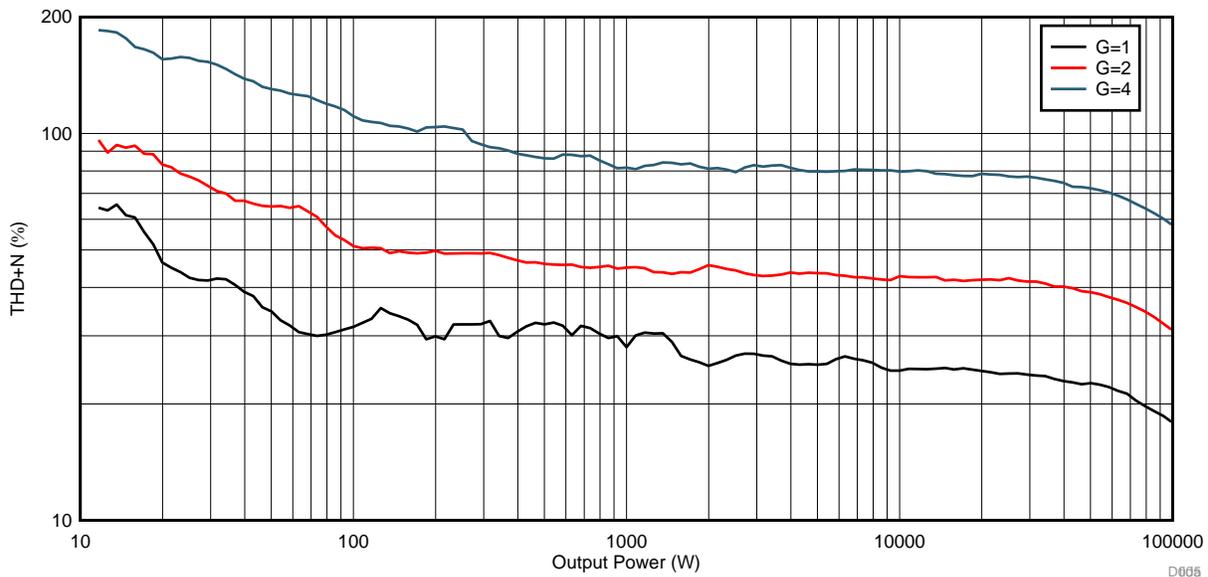


图 2. OPA1632 Preamp Noise

Note that the measured spot noise between 1 kHz and 20 kHz is close to the predicted values of 22.77 nV/√Hz, 39.6nV/√Hz, and 72.58 nV/√Hz for gains of 0 dB, 6 dB, and 12 dB, respectively. The corner frequency, where the flicker noise equals the broadband noise, is approximately 1 kHz. At 20 Hz, the spot noise is roughly twice the magnitude of the broadband noise. However, the sensitivity of the human ear to low sound levels diminishes significantly below 1 kHz, as the audio A-weighting curve in 图 3 shows.

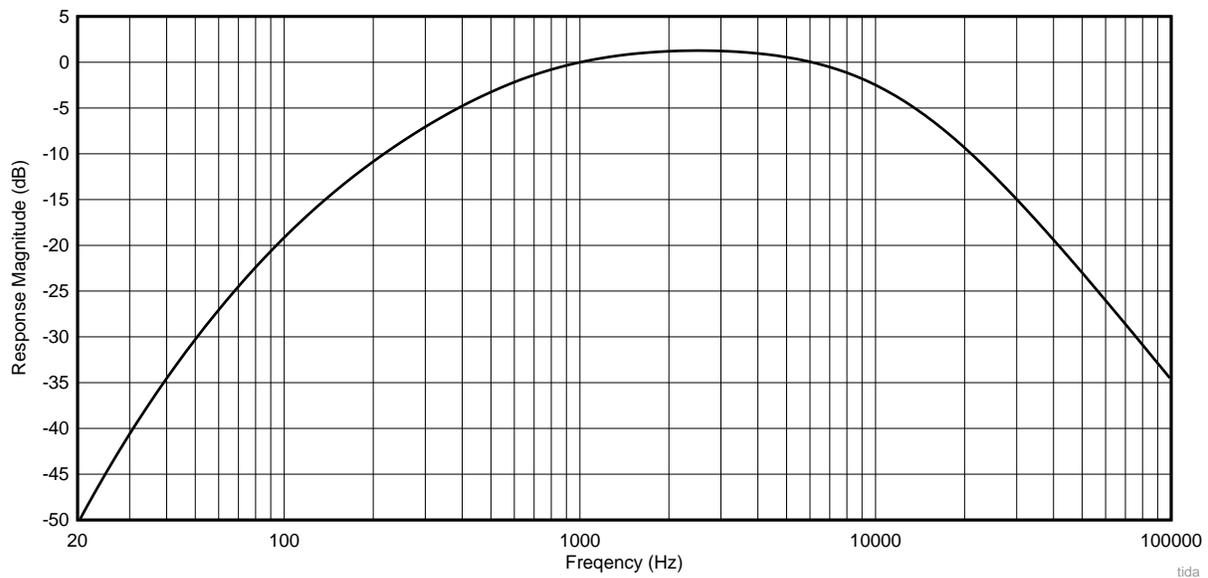


图 3. Audio A-Weighting

The measured A-weighted spot noise in 图 4 shows that the broadband noise from 1 kHz to 6 kHz (95% of which is from the gain-setting resistors) is the only significant perceived noise in the preamp. The voltage and current noise of the OPA1632 are imperceptible compared to the resistor noise of the pre-amp, despite the relatively large gain-setting resistors.

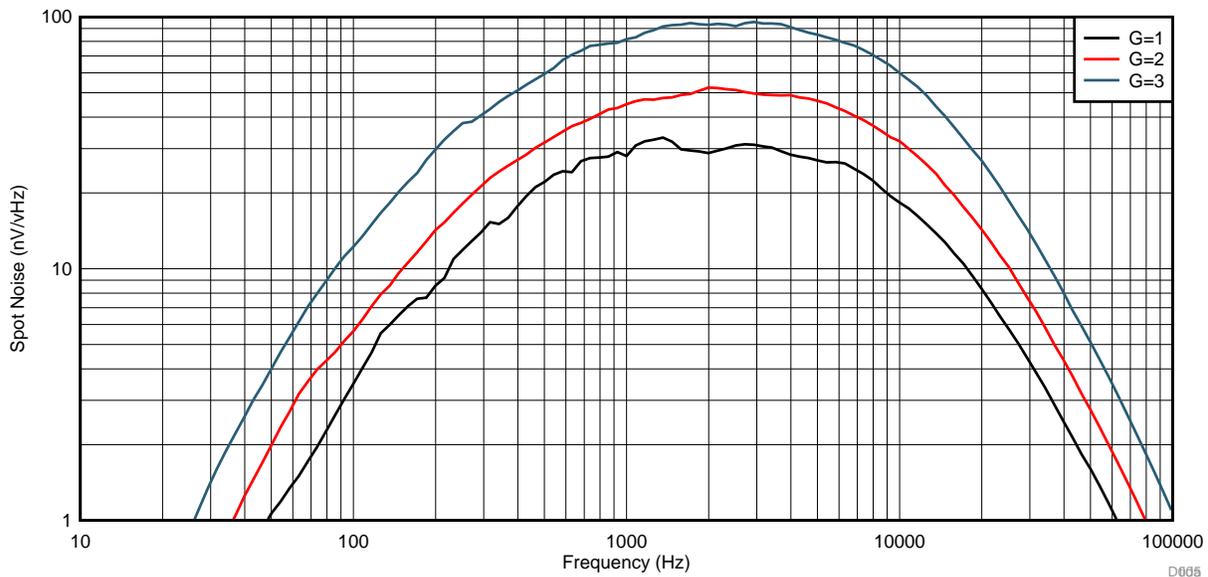


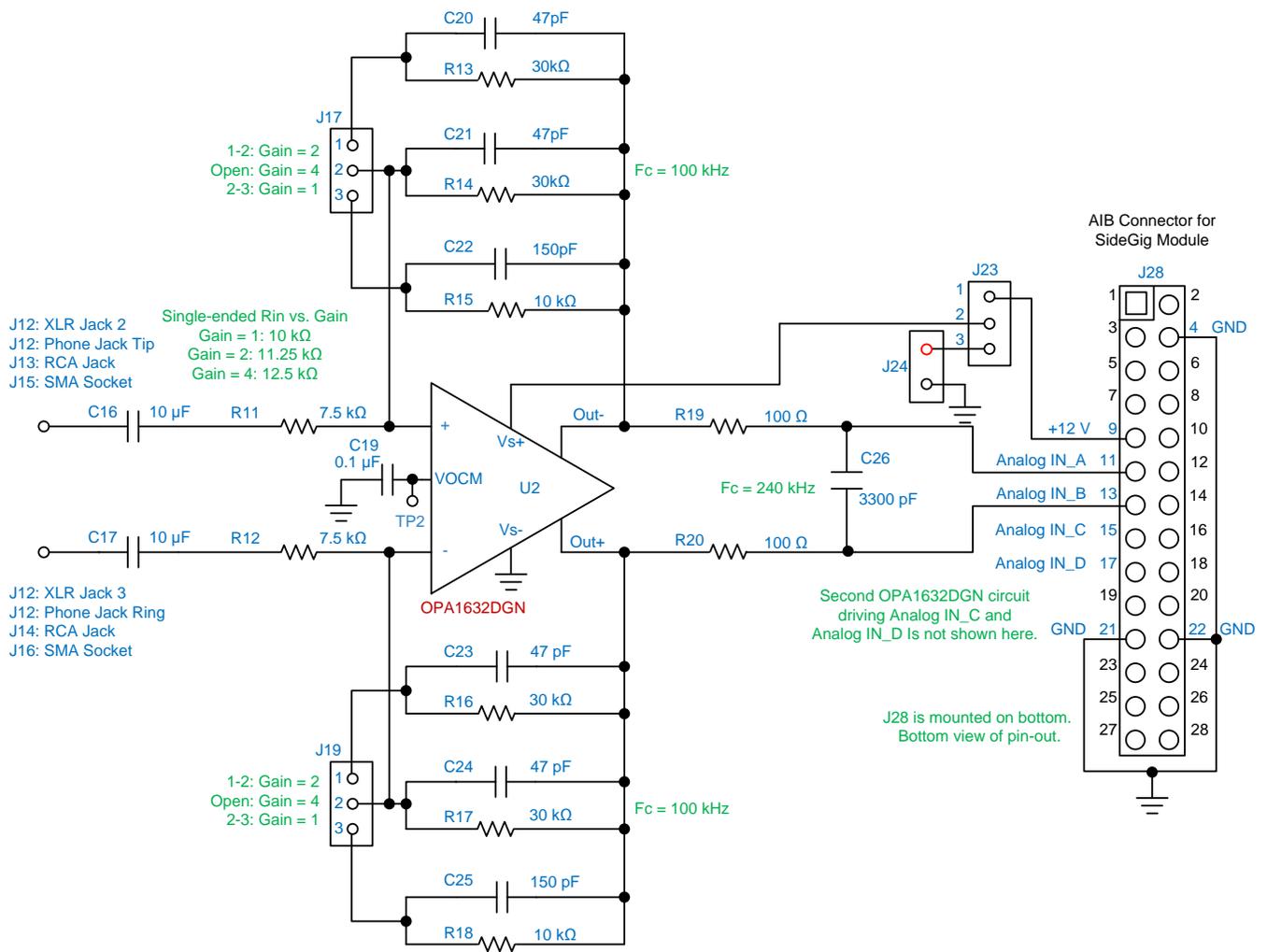
图 4. A-Weighted Spot Noise

If the broadband voltage noise and current noise of another amplifier are significantly higher than that of the OPA1632 device, which are $1.3 \text{ nV}/\sqrt{\text{Hz}}$ and $0.4 \text{ pA}/\sqrt{\text{Hz}}$, respectively, then the noise of the amplifier is perceptible. The same applies if the corner frequency of the flicker noise is significantly higher than that of the OPA1632 device, which has a corner frequency of approximately 1 kHz. This analysis demonstrates that the very low noise of the OPA1632 makes the device designed for an FDA preamplifier with $10\text{-k}\Omega$ input impedance.

The preceding noise analysis is the same for a single-ended or differential input signal. As a result, the OPA1632 reference design is an excellent preamplifier for differential inputs.

2.2.1 System Design Description

图 5 shows a simplified schematic of the Audio-OPA1632EVM. This diagram shows the circuit for the left audio channel.



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图 5. Audio Reference Design Simplified Schematic

图 6 shows a three-dimensional rendering of the Audio-OPA1632 EVM.

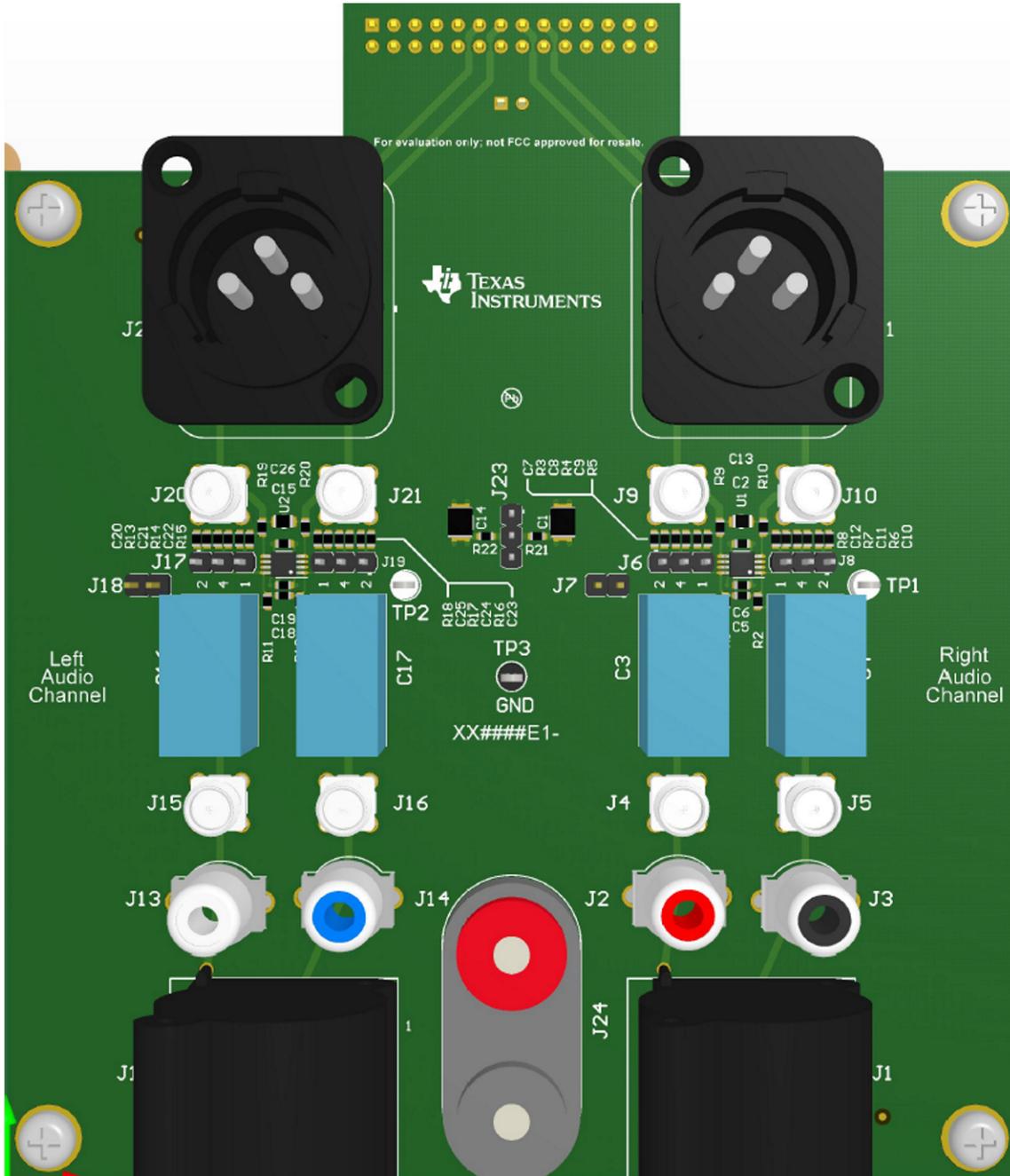


图 6. 3D Rendering of Audio-OPA1632EVM Top Side

表 5 lists the pins used in the AIB connector, J28 on the Audio-OPA1632EVM.

表 5. AIB Connector Pin Descriptions

PIN NUMBER	FUNCTION	DESCRIPTION	AUDIO EVM INPUT/OUTPUT	AUDIO INPUT/OUTPUT
5	GND	Ground reference between Audio and audio class-D EVM	—	—
9	12V	12-V source from EVM; used for powering Audio	O	I
11	Analog IN_A	Analog audio Input A (analog in EVM)	I	O
13	Analog IN_B	Analog audio Input B (analog in EVM)	I	O
15	Analog IN_C	Analog audio Input C (analog in EVM)	I	O
17	Analog IN_D	Analog audio Input D (analog in EVM)	I	O
21	GND	Ground reference between Audio and audio class-D EVM	—	—
22	GND	Ground reference between Audio and audio class-D EVM	—	—

图 7 shows the Neutrik NCJ6FI-H combo input jack (J12 in 图 5 and 图 6), which is a combination XLR and ¼" stereo phone jack.



图 7. Neutrik NCJ6FI-H Combo Input Jack

For a differential input signal, an XLR plug or a ¼" stereo phone (TRS) plug is preferred because these cables preserve the balance of the differential signal. For a single-ended input, these cables can be used, but one side of the signal must be grounded at the source. To ground the negative input for a single-ended input, the source connects the XLR pin 2 or the TRS ring to the source ground. Grounding the input at the source creates less imbalance and the naturally accompanying harmonic distortion than grounding at the Audio-OPA1632EVM input.

Single-ended inputs can be applied with RCA or SMA plugs with a separate cable that supplies the ground for the negative side of the OPA1632 device. In 图 5, J14 or J16 jacks must be grounded at the source.

The Audio-OPA1632EVM has 10-μF polyester DC-blocking capacitors (C16 and C17 in 图 5) on each input. Polyester capacitors are not a general recommendation because the capacitor dielectric must be tailored to the constraints of the application. In this application, polyester capacitors are a reasonable compromise between lower distortion, minimum size, and reasonable cost.

The high-pass cutoff frequency of the DC block is 2.1 Hz for differential inputs and a maximum of 1.6 Hz for a single-ended input. The input impedance for a single-ended input varies with the gain selected for the OPA1632 device due to the changing common-mode voltage at the OPA1632 input. 公式 2 shows the equation for the active impedance experienced by a low impedance single-ended input.:

$$Z_{in} = \frac{2R_g \left(1 + \frac{R_f}{R_g} \right)}{\left(2 + \frac{R_f}{R_g} \right)} \quad (2)$$

where:

- $R_g = 7.5 \text{ k}\Omega$
- $R_f = 7.5 \text{ k}\Omega$, $15 \text{ k}\Omega$, and $30 \text{ k}\Omega$ for gains of 0 dB, 6 dB, and 12 dB, respectively.

Substituting the R_g and R_f values into 公式 2 results in single-ended input impedances of 10 k Ω , 11.25 k Ω , and 12.5 k Ω for gains of 0 dB, 6 dB, and 12 dB, respectively, as 图 5 shows. The selectable gains in V/V are 1, 2, and 4, respectively.

Each R_f resistor has a parallel capacitor to create a low-pass filter cutoff frequency of 100 kHz. Any parallel combination of the R_f resistors preserves the 100-kHz cutoff frequency because the parallel resistance reduces by the same factor as the parallel capacitance increases. R14 and R17 in 图 5 are always in the feedback. The jumper selection in 表 6 must be made on both sides of each OPA1632 amplifier to balance the feedback resistances on each amplifier and to select the same gain on both left and right audio channels. Jumpers J17 and J19 control the gain of the left audio channel. Jumpers J6 and J8 control the gain of the right audio channel.

The silkscreen labels on these jumpers are 2, 4, and 1 corresponding to jumper pins numbers 1, 2, and 3, respectively. The silkscreen labels facilitate selecting the gain: For a gain of 2, short the pins labeled 2 and 4; for a gain of 1, short the pins labeled 1 and 4. For a gain of 4, do not short any pins.

An attenuation of -1.9 dB is achieved by shorting all three pins on each jumper, but this is not a typical configuration of the amplifier.

表 6. Jumper Connections for Selectable Gains

GAIN	CONNECTIONS ON JUMPERS J6, J8, J17, AND J19
12 dB (4 V/V)	Open
6 dB (2 V/V)	Short pins labeled 2 and 4 (pins 1 and 2 of jumpers)
0 dB (1 V/V)	Short pins labeled 1 and 4 (pins 3 and 2 of jumpers)
-1.6 dB (0.8 V/V)	Short pins labeled 1, 2, and 4 (pins 1, 2, and 3 of jumpers)

The output common-mode voltage is set by the OPA1632 VOCM input. When a voltage is not forced on this input, the OPA1632 sets this voltage to midsupply, that is 6 V, when the TPA32xxEVM 12-V supply is selected. Test point TP2 shown in 图 5 is provided in case the user forces a voltage other than midsupply on the VOCM input. Capacitor C19 in 图 5 reduces the noise on this input, which reduces the output common-mode noise. Jumper J23 selects the 12-V supply for the Audio-OPA1632EVM per the connections in 表 7. Short the middle pin on jumper 23 to the pin that is closest to the desired 12-V supply.

表 7. Jumper Connections for Selectable 12-V Power Supply

12-V SUPPLY	CONNECTIONS ON JUMPER J23
TPA32xx AIB connector	Short pins 1 and 2
J24 (external supply)	Short pins 2 and 3

Resistors R19 and R20 and capacitor C26 in 图 5 create a first-order low-pass filter with a cutoff frequency of 240 kHz, which limits the noise bandwidth of the Side-Gig device. The class-D amplifier samples the differential input at the selectable modulation frequency of the pulse-width modulation (PWM) outputs. For the TPA3245EVM, the sample frequency, f_s , is 600 kHz. Due to this input sampling, high-frequency noise can alias back into the audio band; hence, the output filter acts as an antialiasing filter.

All feedback capacitors and capacitor C26 in 图 5 have C0G dielectrics to minimize distortion. 图 8 is sourced from the [Where capacitance coefficients matter](#) forum posting[2] by TI applications engineer Bonnie Baker. This graph shows a comparison of the total harmonic distortion and noise (THD+N) for common capacitor dielectrics. Capacitors do not create noise; therefore, the differences in the THD+N measurements are due to differences in distortion created primarily by the voltage coefficient of capacitance of the various dielectrics.

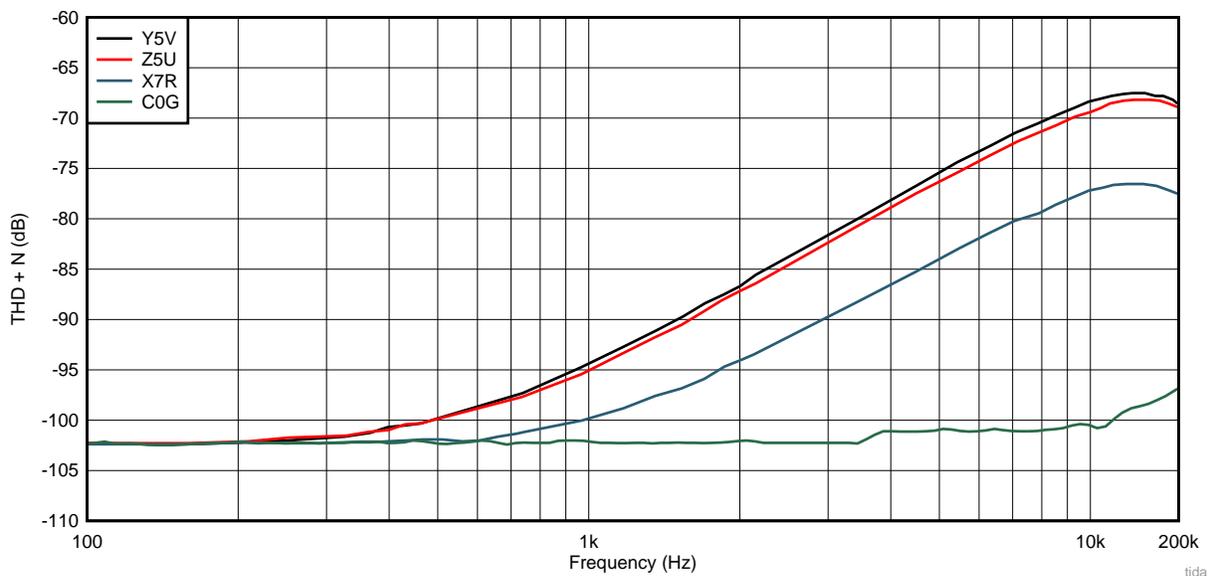


图 8. Distortion for Common Capacitor Dielectrics

For more information, see the [Signal distortion from high-K ceramic capacitors](#) how-to article[3] by TI applications engineer John Caldwell.

2.3 Design Considerations

2.3.1 Class-D EVM Compatibility

This reference design is compatible with analog input class-D EVMs designed with the audio interface board (AIB) connector. This compatibility includes TPA3244, TPA3245, and TPA3255 EVMs. See 表 5 for details on the AIB connector.

2.3.2 Audio Output Type

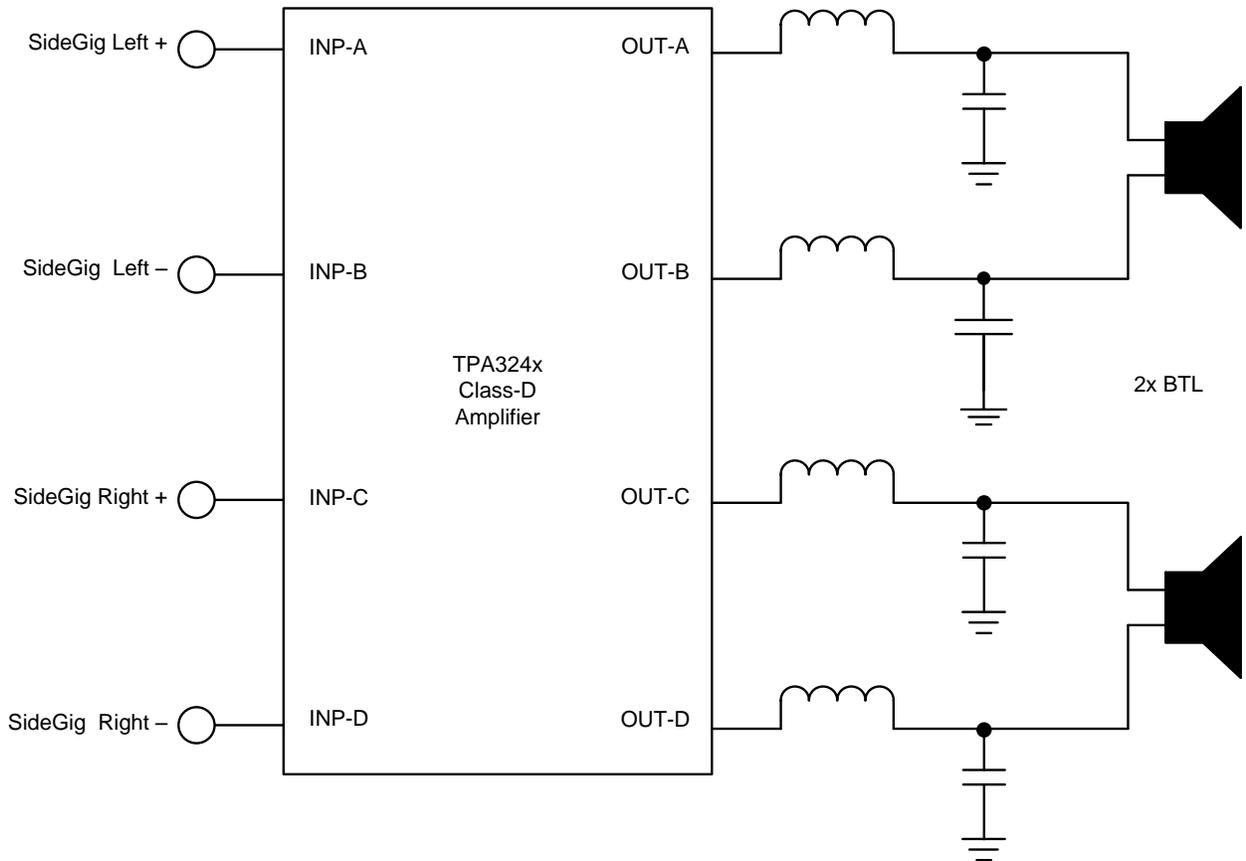
This reference design drives two differential voltage outputs each capable of 5.8 V_{RMS}.

2.3.3 Class-D EVM Input Type

This reference design is only compatible with analog input class-D EVMs with the AIB connector.

2.3.4 Supported Class-D Speaker Configurations

This reference design has two audio channels (labeled left and right) which are designed to drive the two differential-input channels of the TPA32xx amplifier configured for a 2x bridge-tied load (BTL), as [图 9](#) shows.



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图 9. Input and Output Connections of TPA32xx EVM

2.4 Highlighted Products

2.4.1 OPA1632

The OPA1632 device offers the following features:

- Ultra-Low Distortion: 0.000022%
- Low Noise: 1.3 nV/ $\sqrt{\text{Hz}}$
- Fully-Differential Architecture: Balanced Input and Output Converts Single-Ended Input to Balanced Differential Output
- Wide Supply Range: ± 2.5 V to ± 16 V
- Shuts Down to Conserve Power

Historically, converting a single-ended signal into a differential signal has been accomplished with two operational amplifiers (op amps). Both amplifiers add noise and any mismatch in the two amplifiers creates distortion.

A single fully-differential amplifier (FDA) creates a differential output with better matching and hence lower distortion. Given the same flicker and broadband noise in the FDA and op amps, a single FDA amplifier adds half of the noise power compared to two op amps. FDAs have a secondary common-mode feedback loop which helps to reduce common-mode disturbances.

The 180-MHz gain-bandwidth product of the OPA1632 may seem excessive for an audio application, but this high bandwidth greatly reduces the distortion in the audio band. See the TI E2E™ online community forum post titled [Has distortion got your amplifier down? Get more bandwidth!](#)^[4] for why this high bandwidth is useful in an audio application.

2.4.2 TPA3245

The TPA32454 device offers the following features:

- Differential Analog Inputs
- 95-W Stereo into 4 Ω and < 0.01% THS+N to Clipping
- 65-dB Power-Supply Rejection Ratio (BTL, No Input Signal)
- < 50- μ V (A-Weighted) Output Noise and > 112-dB (A-Weighted) Signal-to-Noise Ratio (SNR)
- Signal Bandwidth up to 100 kHz for Content from a High-Definition Source
- 90% Efficient Class-D Operation (4 Ω)

3 Getting Started Hardware

3.1 Hardware

3.1.1 TPA32xx EVM Setup

The TPA32xx EVMs have RCA jack inputs for single-ended and differential inputs. These RCA jacks typically drive NE5532 op amps that drive the inputs to the TPA32xx class-D amplifier. This signal path is the default path whereas, the inputs through the AIB connector, which are used by the Audio-OPA1632EVM, are an optional signal path.

To use the AIB as the signal path to the TPA32xx class-D amplifier, four 0-Ω resistors must be removed to disconnect the default signal path. For the TPA3245EVM (AAP072A), these four resistors are R4, R12, R44, and R46. R4 and R12 are under the heat sink on the top side, which requires removing the heat sink to remove these resistors. Do not remove the thermally-conductive grease from the heat sink and the TPA32xx class-D amplifier. Reinstall the heat sink before operating the TPA32xx device.

For other TPA32xx EVMs, consult the EVM guide for the resistors to remove or for the jumper settings to disconnect the default signal path and connect the AIB signal path.

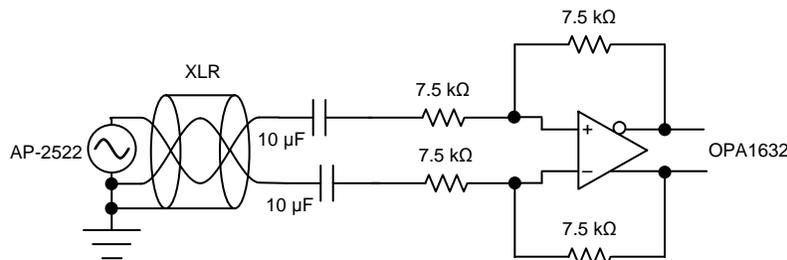
To configure the TPA3245EVM (AAP072A) for double BTL outputs, select INC on jumper J26 and select IND on jumper J27. These selections are made by shorting the lower two pins in each three-pin jumper. The mode-setting jumpers J5 and J6 are set to M1 = M2 = 0 by shorting the lower two pins in each three-pin jumper. The parallel bridge-tied load (PBTL) jumpers J7 and J8 are open. For other EVMs, consult the EVM guide for the jumper settings for double BTL outputs.

The TPA3245EVM supply (PVDD) is driven by an HP6623A power supply set to 30 V. Two channels of the HP6623A are stacked to provide sufficient current.

3.1.2 Audio Precision Measurement Setup

All of the graphs shown in 4 节 were measured using an Audio Precision AP-2522 with an AES17 filter.

The Audio-OPA1632EVM is measured separately using an external 12-V power supply. The single-ended output of the AP-2522 device is connected to the differential input of the Audio-OPA1632EVM using an XLR cable to preserve the balance of the impedances driving the input. 图 10 shows the XLR cable connections to drive a single-ended signal into the Audio-OPA1632EVM. The differential output of the Audio-OPA1632EVM drove the differential input of the AP-2522 device through an XLR cable with the shield grounded.



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图 10. AP-2522 Driving Single-Ended Signal Through XLR Cable

图 11 显示了 AP2700 软件中为控制 AP-2522 设备的模拟生成器设置。

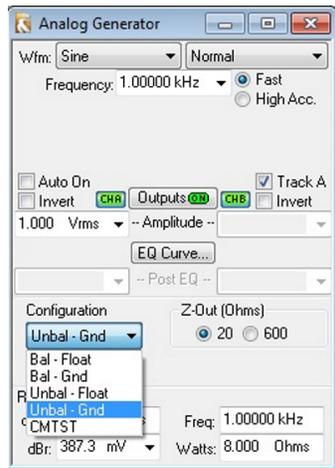


图 11. AP2700 软件设置用于单端输出

AP2700 用户手册提供了图 12 所示的图，这对应于 Unbal-Gnd 输出配置。

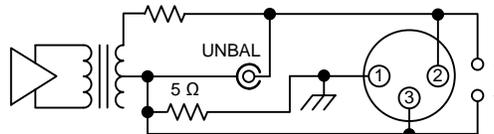


图 12. AP2700 图显示了 Unbal-Gnd 输出配置

TPA3245EVM 的性能是单独测量的，使用 AP-2522 设备的差分输出驱动 TPA3245EVM 的差分输入，通过 XLR 电缆，屏蔽层在 AP-2522 处接地。AP2700 的 Bal-Gnd 输出配置被选中，这连接了 AP-2522 的输出，如图 13 所示。

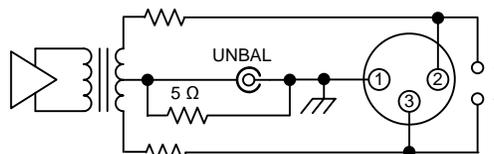


图 13. AP2700 图显示了 Bal-Gnd 输出配置

TPA3245EVM 的差分输出驱动 AP-2522 的差分输入，通过一对带有香蕉插头的双绞线连接到 AP-2522 设备。

Audio-OPA1632EVM 和 TPA3245EVM 的合并性能是通过将 AP-2522 的单端输出信号驱动 Audio-OPA1632EVM 如图 10 所示，以及将 AP-2522 的差分输入与 TPA3245EVM 的差分输出在双 BTL 配置中驱动。

3.1.3 TPA3245EVM Output Loads

For the measurements of the TPA3245EVM and the combined Audio-OPA1632EVM and TPA3245EVM, the differential outputs of the TPA3245EVM were loaded with 3 Ω , 4 Ω , or 8 Ω using Arcol HS200 4- Ω power resistors. The 8- Ω load consists of two Arcol resistors in series. The 3- Ω load consists of one Arcol 4- Ω resistor in parallel with three Arcol 4- Ω resistors in series: $1 / 3 = 1 / (1 / 4 + 1 / 12)$.

4 Testing and Results

All performance plots in this section are measured data produced from the "Audio-TIDA01359EVM" board. The design files (GERBER, BOM, schematic and layout layers) are included in the reference design documentation found in the product folder. [TIDA-01359](#)

The main objective of the performance measurements was to compare the noise and distortion of the Audio-OPA1632EVM to the TPA3245EVM. Based on the specifications of the OPA1632 and the TPA3245, the noise and distortion of the OPA1632 preamplifier converting a single-ended signal into a differential signal must be significantly lower than the noise and distortion of the TPA3245 device amplifying a differential input signal and driving a differential resistive load.

This expected performance difference is fundamentally due to the large currents driven by the TPA3245EVM compared to the small loads of the Audio-OPA1632EVM. The hypothesis is that the noise and distortion contributed by the Audio-OPA1632EVM preamplifier does not measurably degrade the performance of the TPA3245EVM. The combined performance of the Audio-OPA1632EVM and TPA3245EVM was measured and compared to the TPA3245EVM performance to test this hypothesis.

The harmonic distortion (HD) of a single tone and the intermodulation distortion (IMD) of two tones were measured. The IMD was measured using the SMPTE4:1 standard implemented by the AP-2522.

4.1 THD+N Comparisons

图 14 shows the THD+N comparisons of the AP2522, OPA1632EVM, TPA3245EVM, and the combined OPA1632EVM and TPA3245EVM. The signal frequency was 1 kHz with the signal power varied to produce an TPA3245EVM output signal into a 4-Ω resistor from 10 mW to 100 W. The OPA1632 was configured for a gain of 0 dB (1 V/V) and the TPA3245EVM supply voltage was set to 30 V. The sample frequency of the TPA3245 was 600 kHz.

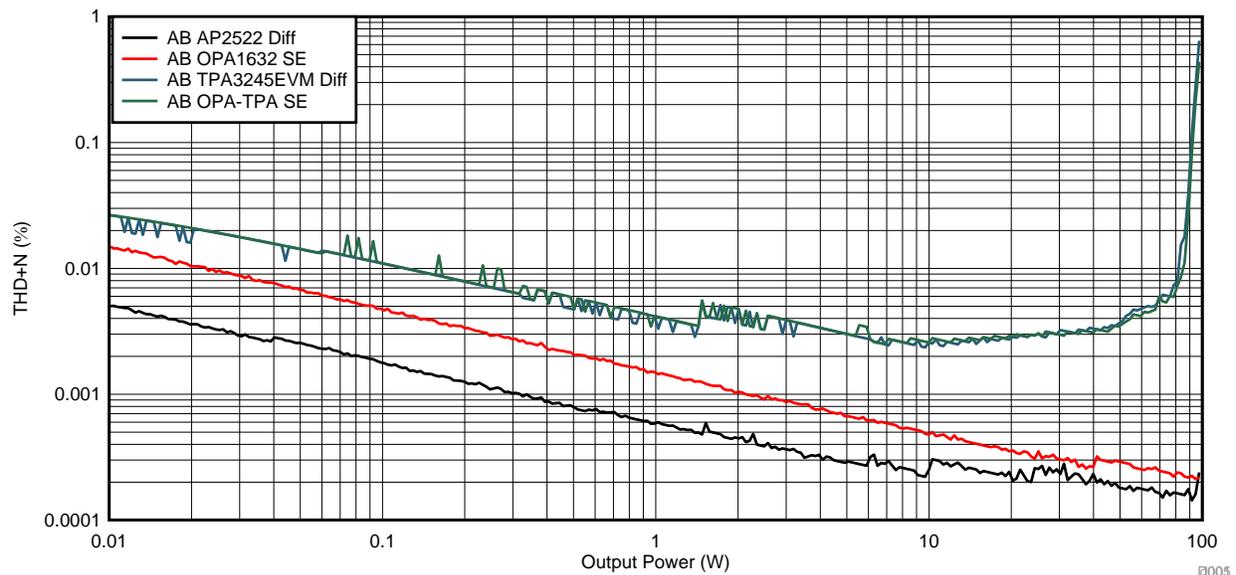


图 14. THD+N Comparisons of AP2522, OPA1632EVM, and TPA3245EVM With 4-Ω Load

The black line plotted in 图 14 is the performance of the AP2522 driving a differential output through an XLR cable to its differential inputs. This graph establishes the performance of the measurement system; therefore, all subsequent measurements must have a higher THD+N as a percentage of the output signal.

The red line plotted in 图 14 is the THD+N of a single-ended signal from the AP2522 converted to a differential signal by the OPA1632 device. Note that the THD+N of the OPA1632 at the lowest power level is about three times worse than the AP2522. However, the output configuration of the AP2522 was differential when measuring the AP2522 and single-ended when measuring the OPA1632. Some of the degradation in the OPA1632 measurement is likely due to the change in the AP2522 output configuration, but this degradation cannot be easily measured.

The near constant slope of the AP2522 and OPA1632 graphs below 1 W of the TPA3245EVM output implies that the performances of the AP2522 and OPA1632 are dominated by noise. The OPA1632 THD+N reduces by a factor of 10.4 from 10 mV to 1 W, which is a 100x increase in power. Because the THD+N has units of V_{RMS} , the square of THD+N has units of V_{RMS}^2 , which is proportional to power. The reduction factor in $THD+N^2$ is $10.4^2 = 108.2$, which is close to the 100x increase in signal power and also demonstrates that the OPA1632 performance is limited by a constant output noise and not by harmonic distortion.

Above the signal power to produce a 10-W TPA3245EVM output, the AP2522 graph starts to flatten, which indicates that distortion is becoming significant. Similarly, the OPA1632 graph starts to flatten above 40 W of system output.

The second-highest line plot (blue) in 图 14 is the TPA3245EVM THD+N performance. Note that this data plot is 1.77 times higher than the OPA1632 plot at 10 mW and that the ratios grow as the power increases. The distortion of the TPA3245EVM starts to dominate the performance at about 7 W and starts to increase exponentially above 50 W. The spikes on the TPA3245EVM data below 3 W of output power are aliasing effects caused by the 600-kHz sample frequency.

The topmost line plot (teal) in 图 14 is the combined THD+N of the OPA1632EVM driving the TPA3245EVM. This data plot essentially overlays the previous data plot and implies that the noise and distortion of the OPA1632EVM is insignificant compared to the TPA3245EVM. As mentioned previously, this result is not surprising given that the OPA1632EVM is driving a high impedance and the TPA3245EVM is driving 4 Ω after amplifying the signal by 18 dB (7.94 V/V).

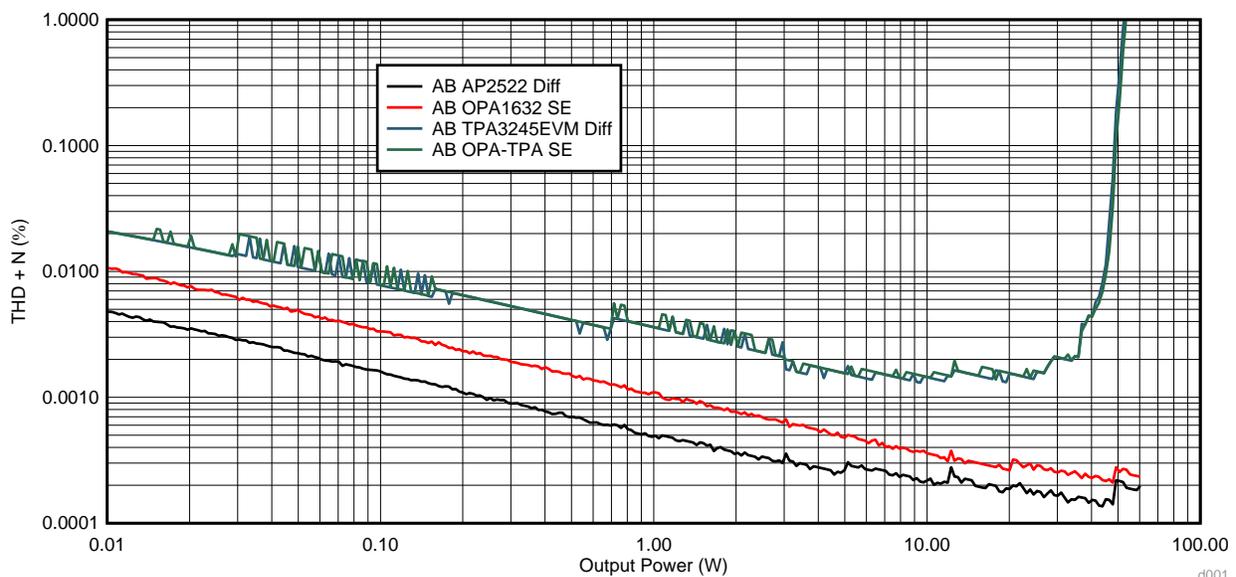


图 15. THD+N Comparisons of AP2522, OPA1632EVM, and TPA3245EVM With 8- Ω Load

The same observations on the THD+N with the 4-Ω load apply to the 8-Ω load except that the distortion becomes significant at lower power levels due to the higher output voltage for the same power level with the 4-Ω load.

Recall that the output noise of the OPA1632EVM with a gain of 12 dB is significantly higher than the noise with a gain of 0 dB. This result is primarily due to the gain applied to the noise from the R_g resistors. The higher noise with a gain of 12 dB is discernable below about 10 W of output power, as 图 16 shows.

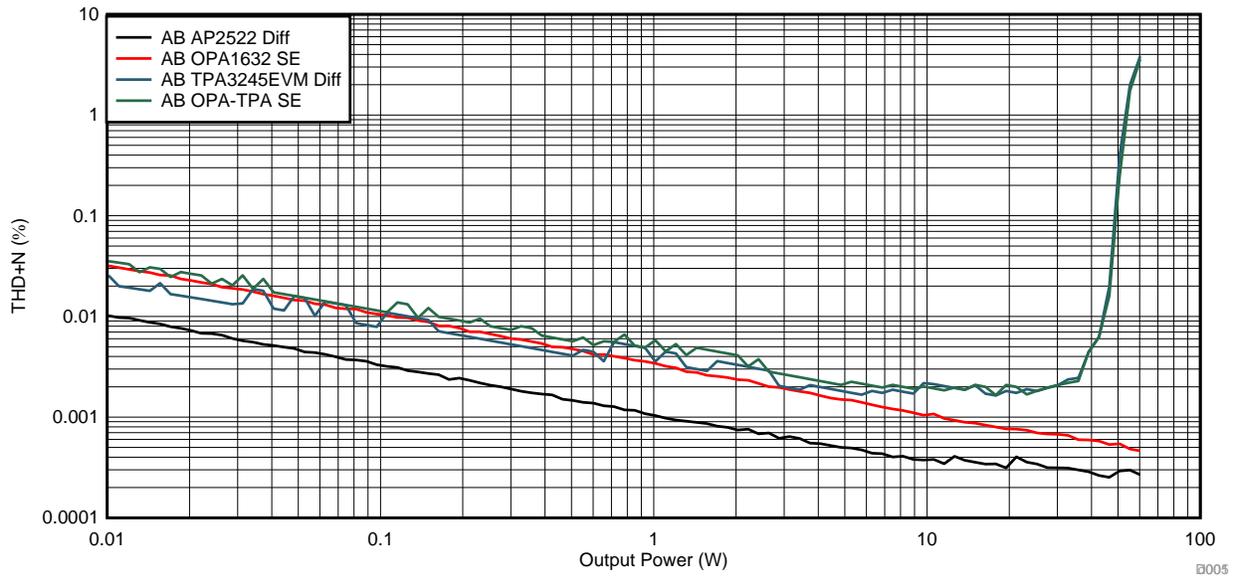


图 16. THD+N versus Output Comparisons of AP2522, OPA1632EVM G = 12 dB, and TPA3245EVM

Note that the output noise from the OPA1632EVM is higher than the noise from the TPA3245EVM below 600 mW and the noise of the combined signal path is higher than the TPA3245EVM noise below 8 W. This result is the only discernable degradation in performance observed in the combined signal path compared to the TPA3245EVM.

The distortion of the TPA3245EVM increases sharply with frequency at about 400 Hz, but the distortion of the OPA1632EVM is flat across the frequency band, which 图 17 shows.

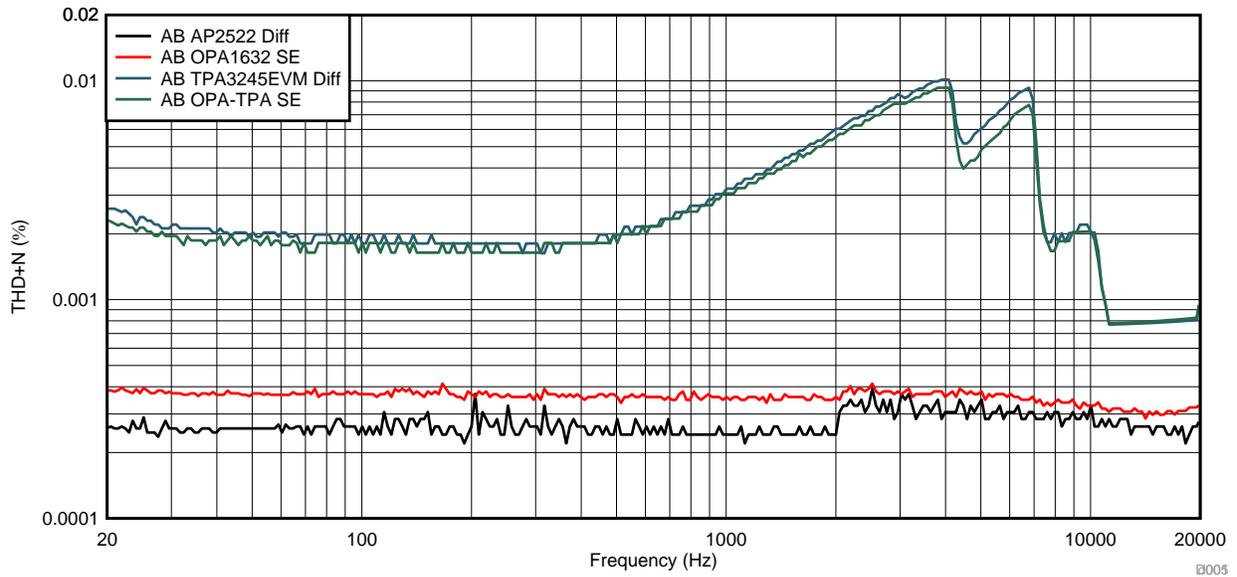


图 17. THD+N vs Frequency Comparisons of AP2522, OPA1632EVM, and TPA3245EVM

4.2 Intermodulation Distortion (IMD) Comparisons

The IMD performance of the various components versus amplitude is shown in 图 18 while the performance over frequency appears in 图 19. The OPA1632EVM IMD is indiscernible in the IMD of the combined OPA1632EVM and TPA3245EVM signal path.

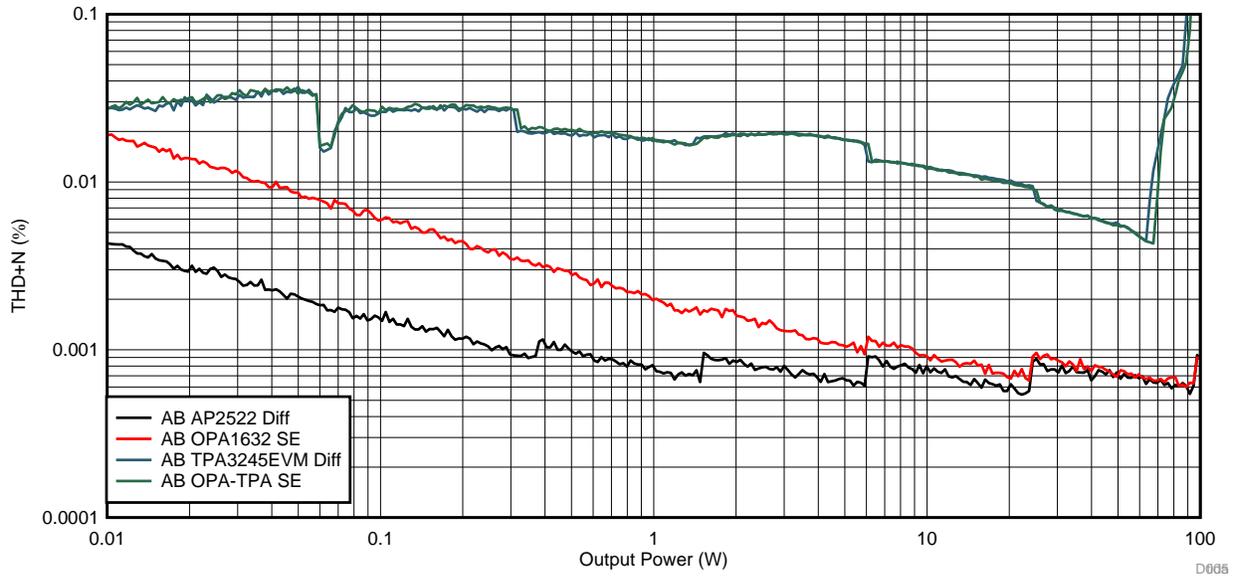


图 18. IMD vs Output Comparisons of AP2522, OPA1632EVM, and TPA3245EVM

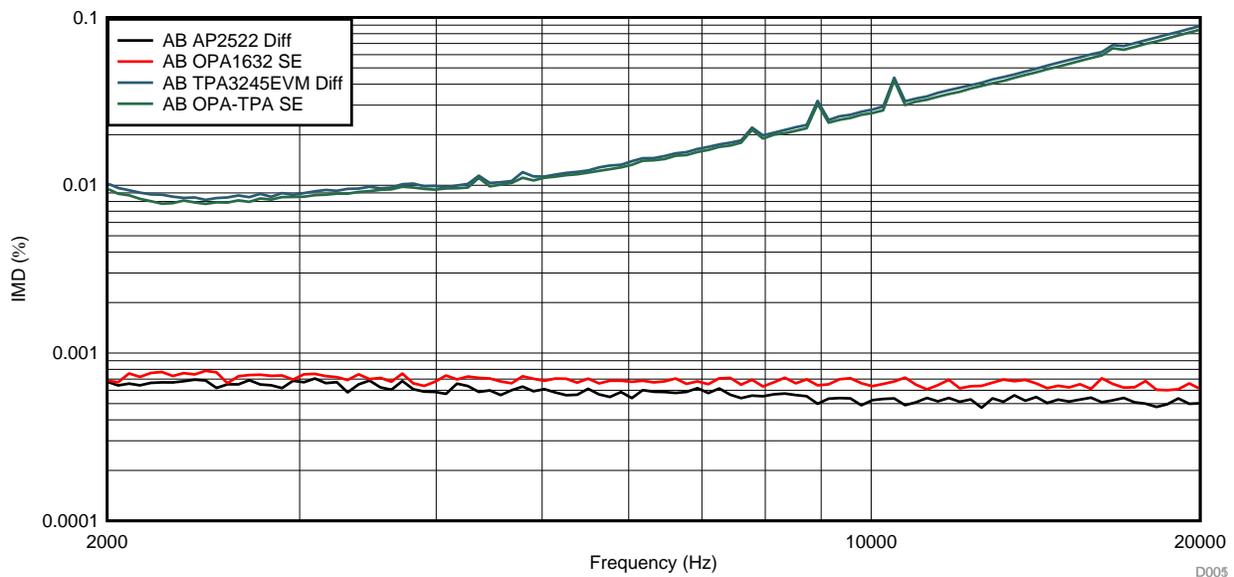


图 19. IMD vs Frequency Comparisons of AP2522, OPA1632EVM, and TPA3245EVM

The lowest frequency is 2 kHz because the SMPTE IMD test uses a fixed 60-Hz tone and a variable high-frequency tone starting at 2 kHz. Note that the OPA1632EVM performance is slightly worse than the AP2522 performance in this test.

4.3 Summary of Performance Comparisons

The harmonic distortion and intermodulation distortion of the OPA1632EVM converting a single-ended signal to a differential signal is far superior to the TPA3245EVM at all frequencies and power levels.

The output noise of the OPA1632EVM with a 0-dB gain configuration is superior to the TPA3245EVM output noise and is indiscernible in the overall system noise.

The output noise of the OPA1632EVM with a 12-dB gain configuration is discernable in the overall system noise at output levels below 8 W. The OPA1632EVM noise with 12-dB gain is primarily due to the noise from the R_g resistors. If lower input impedance of the OPA1632EVM is acceptable, this noise can be decreased by scaling down the R_g and R_f resistors that set the gain of the OPA1632EVM.

5 Design Files

5.1 Schematics

To download the schematics, see the design files at [TIDA-01359](#).

5.2 Bill of Materials

To download the bill of materials (BOM), see the design files at [TIDA-01359](#).

5.3 PCB Layout Recommendations

5.3.1 Layout Prints

To download the layer plots, see the design files at [TIDA-01359](#).

5.4 Altium Project

To download the Altium project files, see the design files at [TIDA-01359](#).

5.5 Gerber Files

To download the Gerber files, see the design files at [TIDA-01359](#).

5.6 Assembly Drawings

To download the assembly drawings, see the design files at [TIDA-01359](#).

6 Software Files

To download the software files, see the design files at [TIDA-01359](#).

7 Related Documentation

1. Texas Instruments; Kariki, Jim; [Analysis of full differential amplifiers](#), Technical Brief (SLYT157)
2. Texas Instruments; Baker, Bonnie; [Where capacitance coefficients matter](#), TI E2E™ Online Community Forum Posting (Feb 2014)
3. EDN.com; Caldwell, John; [Signal distortion from high-K ceramic capacitors](#), EDN Network How-To Article (June 2013)
4. Texas Instruments; Comeaux, Wayne; [Has distortion got your amplifier down? Get more bandwidth!](#), TI E2E™ Online Community Forum Posting (Dec 2015)
- 5.

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8 About the Author

WAYNE COMEAUX is an applications engineer with TI in the high-speed amplifier division in Tucson, AZ. He validates the performance and specifications of high-speed amplifiers and provides customer support through TI online forums, application notes, and reference designs.

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